

First principle investigation of the structural, electronic, optical, and elastic properties of Ba-based fluoroperovskite (BaYF_3 ; $\text{Y} = \text{Li, Na, K, and Rb}$) compounds

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Original Research

Abstract:

Received:
26 June 2024
Revised:
20 August 2024
Accepted:
23 August 2024
Published online:
30 October 2024

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The BaYF_3 ($\text{Y} = \text{Li, Na, K, and Rb}$) materials as cubic fluoro-perovskite compounds were examined by exploiting the full electron potential technique (FP-LAPW) and DFT through space of the Wien2k package to analyze their electronic and optical characteristics. The structural characteristics were determined through the generalized gradient approximation PBE-GGA functional, while the TB-mBJ functional was applied to enhance the calculation of electronic and optical characteristics. By substituting the cation Y from Li to Na, K, and Rb elements, the lattice constant experiences an increase, but the bulk modulus undergoes a drop. By studying the density of states and energy band structure, it is evident that BaYF_3 ($\text{Y} = \text{Li, Na, K, or Rb}$) exhibits a direct ($\Gamma - \Gamma$) energy band gap as insulator compounds. The obtained band gaps are 8.33 eV for BaLiF_3 , 7.75 eV for BaNaF_3 , 6.27 eV for BaKF_3 , and 5.35 eV for BaRbF_3 . The dielectric function and some connected optical characteristics, including refractive index, absorption coefficient, extinction coefficient, and reflectivity, have been evaluated in the 0 – 30 eV energy range. Due to their excellent absorption and reflection capabilities in the UV spectrum, we prefer exploiting these compounds for optoelectronic applications, specifically in the UV region. Also, we have characterized the elastic constants (C_{11} , C_{12} , and C_{44}) of the perovskite BaYF_3 compounds and their corresponding mechanical parameters by using WC-GGA approximation.

Keywords: Fluoroperovskite; First principle investigation; Optical properties; Structural properties; Elastic properties

1. Introduction

Among various materials, the cubic perovskite family with ABX_3 crystal structure, especially fluoro-perovskite ABF_3 , has garnered increasing attention due to their numerous valuable applications across several industries. These applications include renewable energy generation [1], spintronic applications [2], photovoltaic systems [3], coating materials [4], and fuel cells [5]. Arranging the atomic structure of fluoroperovskite ABF_3 compounds is created by exploiting several alkalis and alkaline earth metals as A and B cations, with fluorine serving as the anion [6, 7]. The vast perovskite family involving fluoroperovskite has received notice for its unique physical characteristics, including UV

transparency, high electron mobility [8], dielectric property [9], piezoelectricity, and magnetism [10]. Fluoroperovskite solids have garnered major attention in the fields of lenses and semiconductors [11]. The main reason for using cubic perovskite in lenses is its low birefringence. These compounds exhibit a significant characteristic in the form of a broad energy band gap. These materials, with their limited absorption edges, can be utilized in the production of glass materials that efficiently transmit vacuum ultraviolet (VUV) and ultraviolet (UV) wavelengths [12].

Kohi et al. conducted an experimental study by using an extreme free electron laser (EUV-FEL) to excite crystals of KMgF_3 and BaLiF_3 compounds. They noted that the energy gaps of these substances were approximately 7.75

eV and 8.41 eV, respectively [13]. Theoretical analysis suggests that BaLiF₃, CaLiF₃, and SrLiF₃ possess highly favorable electronic and optical characteristics, leading them to be used as excellent candidates in optical devices [14]. Mubarak et al. discovered a significant and direct ($\Gamma - \Gamma$) band gap in BaLiF₃, BaKF₃, BaRbF₃, and BaNaF₃ fluoroperovskites by applying first principle calculations. They also observed notable anisotropic behavior at both high and low energy levels [15].

This study primarily investigates the electronic, structural, optical, and elastic characteristics of barium-based fluoroperovskite compounds, namely BaYF₃, with Y being Li, Na, K, and Rb. The band gap was estimated using DFT with PBE-GGA approximation, and to avoid the limitations of PBE-GGA, we have augmented calculations by using the recently updated Becke-Johnson (mBJ) functional. This ensures a close match between the calculated energy gap results and the experimental values. Also, mBJ is adopted to complete other optical parameters involving dielectric function with their related refractive index, absorption, extinction, and reflectivity. The purpose of this study is to offer reliable and precise predictions for the BaYF₃ compounds. To do this, we employed the approximations of the TB-mBJ (optical properties) and WC-GGA (elastic properties) in conjunction with the (FP-LAPW) method carried out through the space WIEN2K program. We would like to draw attention to some previous studies that have used the mBJ approximation to enhance band gap values compared to experimental values [16–21].

2. Computational method

The BaYF₃ crystal is analyzed as a cubic structure with the space group (221) pm-3m. The crystal geometry of the BaYF₃ compound is displayed in Figure 1. The Ba atom is positioned at the coordinates (0.0, 0.0, 0.0), whereas the Y atom (Li, Na, K, and Rb) is positioned at the coordinates (0.5, 0.5, 0.5), and the F atom is placed at the coordinates (0.5, 0.5, 0.0), (0.0, 0.5, 0.5), and (0.5, 0.0, 0.5). The geometrical relaxation was performed to adjust the locations of the atoms and minimize the forces acting on them (1 mRy/Å). The PBE-GGA approximation has been incorporated into the WIEN2K program, applying the complete capabilities of the linearized augmented plane wave (FP-LAPW) method [22, 23]. The electronic structure and associated electronic characteristics were estimated using the relaxed geometry obtained by PBE-GGA. To provide accurate estimations of band gaps and optical characteristics, the latest modified Becke-Johnson (mBJ) potential was utilized [16]. The elastic calculations of BaYF₃ crystal were separately checked using the new form of GGA approximation, which was developed by Wu and Cohen (WC-GGA) [24]. The basis functions were created using a spherically symmetric potential within the spheres while remaining constant outside the spheres [23]. The value of RMT is selected to be 2.5, 2.0, 1.8, 1.95, 2.0, and 2.0 a.u. for Ba, F, Li, Na, K, and Rb atoms, respectively. The convergence of the total energy was achieved by expanding the basis functions up to a maximum value of $RMT \cdot K_{max} = 7.0$ within crystal space. We were taken (-6 Ry) as an

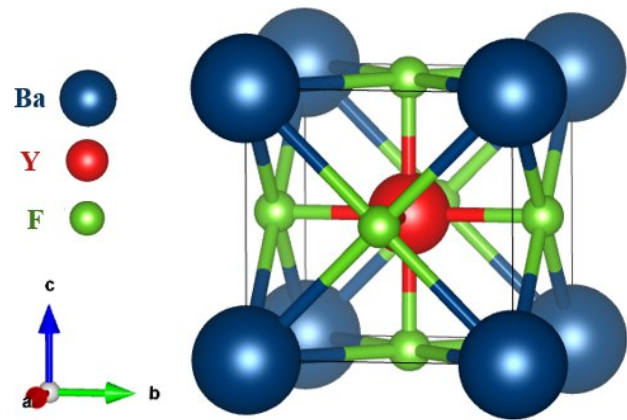


Figure 1. The atomic distribution within the unit cell of BaYF₃ compounds.

energy difference separating the core and valence states. The upper value for L was controlled to be $L_{max} = 10$, while G_{Max} was controlled by Fourier expansion up to 12 (a.u⁻¹) to reduce the charge density. A total of 3000 K-points are utilized for sampling the initial Brillouin zone in reciprocal space to compute the relaxation dynamics, electronic, and elastic properties. To achieve total energy convergence, the self-consistency convergence threshold is set to 0.0001 Ry.

3. Results and discussion

3.1 Structural properties

Here, we examined BaYF₃'s cubic structure. The DFT calculations were conducted to complete the geometrical optimization by applying the PBE-GGA approach to accurately handle the exchange-correlation potential. The process of volume optimization starts by altering the volume, both decreasing and increasing it around the equilibrium volume. The changes in volume led to a consistent alteration in the internal energy for unit cell volume. Figure 2 exhibits the link between the changed volume and the related variations in total energy. The Murnaghan equation was employed to fit this plot and determined the values of the equilibrium state parameters such as lattice constant (a_0), bulk modulus (B_0) and derivative of bulk modulus (\dot{B}_0) for each compound [26]. These acquired parameters are compared to the previously conducted theoretical and available experimental studies, as detailed in Table 1. The equilibrium state yields lattice constants of 4.042 Å for BaLiF₃, 4.275 Å for BaNaF₃, 4.724 Å for BaKF₃, and 4.977 Å for BaRbF₃. The lattice constant of the BaYF₃ crystal increased as the Y position shifted from Li to Rb, respectively. However, the bulk modulus dropped in the same direction of shifting. The computed lattice constants revealed a remarkable agreement with earlier theoretical results [15, 27], while the lattice constant of BaLiF₃ was found to be higher than the experimental value [25]. We employed these optimum parameters to ascertain the optical and electronic characteristics of the bulk BaYF₃. Figure 1 indicates the crystal composition of the bulk BaYF₃ and the equilibrium constants (a_0 , B_0 , and \dot{B}_0) are given in Table 1.

3.2 Electronic properties

Analyzing the electronic characteristics is essential for obtaining an extensive knowledge of the structure and internal interactions within the atomic energy bands of materials and assessing the material efficiency for a specific application [28]. Therefore, we focused on comprehending the electronic characteristics of the bulk BaYF₃ (Y = Li, Na, K, and Rb).

We have analyzed the band structure, as shown in Figure 3. These calculations were performed using the optimal geometrical parameters listed in Table 1. We conducted band structure calculations using the PBE-GGA and enhanced by mBJ approximation, as indicated in Table 2. As mentioned previously, it may be concluded that mBJ enhances calculations of energy band gaps in comparison with PBE-GGA. We only utilized mBJ to analyze additional electronic properties, specifically TDOS and PDOS. The valence band (VB) maxima and conduction band (CB) minima of these compounds have their highest and lowest energy levels positioned at the gamma ($\Gamma - \Gamma$) point of the Brillion Zone, giving direct band gaps of about 6.74 eV, 6.16 eV, 4.48 eV, and 3.42 eV (PBE-GGA) and approximately 8.33 eV, 7.75 eV, 6.27 eV, and 5.35 eV (mBJ) for the BaLiF₃, BaNaF₃, BaKF₃, and BaRbF₃ compounds, respectively. The energy band gap values of BaYF₃ were consistently reduced as the Y-site atom was switched from Li to Rb. In this scenario, BaLiF₃ has a higher band gap value, whereas BaRbF₃ has a lower band gap value. Therefore, by substituting Y-site with Li, Na, K, and Rb atoms, the energy band gaps of the insulators under consideration can be modified in certain

Table 1. Some equilibrium parameters of BaYF₃ (Y = Li, Na, K, and Rb) were obtained from the structural relaxation process within the PBE-GGA approximation.

Compounds	a_o (Å)	B_o (GPa)	\acute{B}_o
BaLiF ₃			
This work (PBE)	4.042	66.85	4.64
PBE [15]	4.04	66.46	5.17
PBE [15]	4.043	66.18	4.72
Exp [25]	3.996		
BaNaF ₃			
This work (PBE)	4.275	52.77	4.53
PBE [15]	4.28	55.28	4.61
BaKF ₃			
This work (PBE)	4.724	36.55	4.69
PBE [15]	4.72	37.48	4.51
BaRbF ₃			
This work(PBE)	4.977	29.28	4.49
PBE [15]	4.96	31.72	4.66

Table 2. The determined energy band gaps (E_g) within TB-mBJ and PBE-GGA approaches for BaYF₃ compounds, where Y denotes the elements Li, Na, K, and Rb.

Compounds	E_g (eV)
BaLiF ₃	
This work (mBJ)	8.33
This work (PBE)	6.74
MBJ [27]	8.26
PBE [27]	6.72
PBE [15]	6.8
Exp [13]	8.41
BaNaF ₃	
This work (mBJ)	7.75
This work(PBE)	6.16
PBE [15]	6.1
BaKF ₃	
This work (mBJ)	6.27
This work (PBE)	4.48
PBE [15]	4.6
BaRbF ₃	
This work (mBJ)	5.35
This work (PBE)	3.42
PBE [15]	3.7

applications, making them very appropriate for employment in optoelectronic devices. The energy band gaps observed with PBE-GGA show a significant agreement with earlier theoretical research by PBE in reference [15]. Except for the BaLiF₃ compound, experimental data concerning the band gaps of these Ba (Na, K, and Rb) F₃ is currently unknown. The experimental band gap for BaLiF₃ is 8.41 eV [13], which is higher than our and prior mBJ and PBE theoretical computations [15, 27]. It is evident that the mBJ method significantly improves the calculated band gap for BaLiF₃, bringing it closer to the experimental value. Therefore, we anticipate that the mBJ method will also enhance the band gaps for BaNaF₃, BaKF₃, and BaRbF₃ compounds, making them more accurate compared to future experimental calculations than the PBE-GGA method. Consequently, we focused only on showing the findings generated by exploiting the mBJ approach.

Also, we only utilized mBJ to analyze additional electronic properties, specifically the total density of atomic states TDOS and the related partial contributions of the atom's orbital states PDOS. The valence states Ba-*s*, *p*, *d*, Li-*s*, *p*, and F-*s*, *p* were selected for the purpose of computing the TDOS and PDOS of each compound. The Fermi energy level was

established at 0.0 eV, while the energy of the photon ranges from 15 to -30 eV. Figure 4 depicts the contributions of atoms, which construct the total density of states of BaYF₃. As we can see, the conduction bands of each compound are dominated by contributions of Ba atoms, whereas the valence bands are mainly dominated by the F atom in the energy spectrum from 0 to -5 eV near the Fermi level, with small contributions of Ba and Y atoms located from (-7) to (-30) eV. Figure 4 also shows the partial contributions of the atom's orbitals. As we see from the PDOS distribution of orbitals in Figure 4, the conduction bands of each compound are significantly dominated by Ba-5*d* with a small contribution of F-2*P* states, while the valence bands are mostly influenced by the F-2*p* state within the energy span from 0 to -5 eV with different small contributions of Y-*s*, *p*, Ba-*s*, *p*, and F-*s* states centered along the energy spectrum from -7 to -30 eV.

3.3 Optical characteristics

Investigation of the optical characteristics of BaYF₃ (X = Li, Na, K, and Rb) perovskite compounds enables us to accurately illustrate their various utilizations and probable applications in the optoelectronics field. Also from a deeper side, electronic transitions affect a material's optical characteristics and suitability for optical applications. There are two categories of electronic transitions that occur within solid materials. The first type is interband transfers. This phenomenon arises when charge carriers are stimulated to

move from the valence band (VB) to the conduction band (CB). This transfer can occur through two methods: either directly or indirectly. The second category is intraband transitions, which refers to the movement of electrons within the same energy band in a material. In insulating materials, intraband transitions within the same bands are ignored, but transfers between the VB and CB are considered in the presence of high excitation energy [29, 30]. Depending on the improved band gap results as indicated above in Table 2, the TB-mBJ approach is adopted to obtain the optical characteristics of BaYF₃ compounds with energy (0–30) eV.

The dielectric function $\epsilon(\omega) = \epsilon_1(\omega) + i\epsilon_2(\omega)$ is employed to represent the connection between the electronic structure of the system and the tiny physical transitions occurring between energy bands. The real $\epsilon_1(\omega)$ and the imaginary $\epsilon_2(\omega)$ components are provided in the equations below [31].

$$\epsilon_1(\omega) = 1 + \frac{2}{\pi} P \int_0^{\infty} \frac{\omega' \epsilon_2(\omega')}{\omega'^2 - \omega^2} d\omega' \quad (1)$$

$$\epsilon_2(\omega) = \frac{2e^2}{\Omega \epsilon_0} \sum_{K,V,C} |\langle \Psi_K^C | U, r | \Psi_K^V \rangle|^2 (E_K^C - E_K^V - E) \quad (2)$$

where Ψ_K^C and Ψ_K^V refer to the wave functions at a certain K in the CB and VB, respectively, Ω and e indicate the unit cell volume and the electronic charge, respectively, the unit vector U describes the polarization of the incoming electric field, E_K^C and E_K^V indicate the energy of electrons

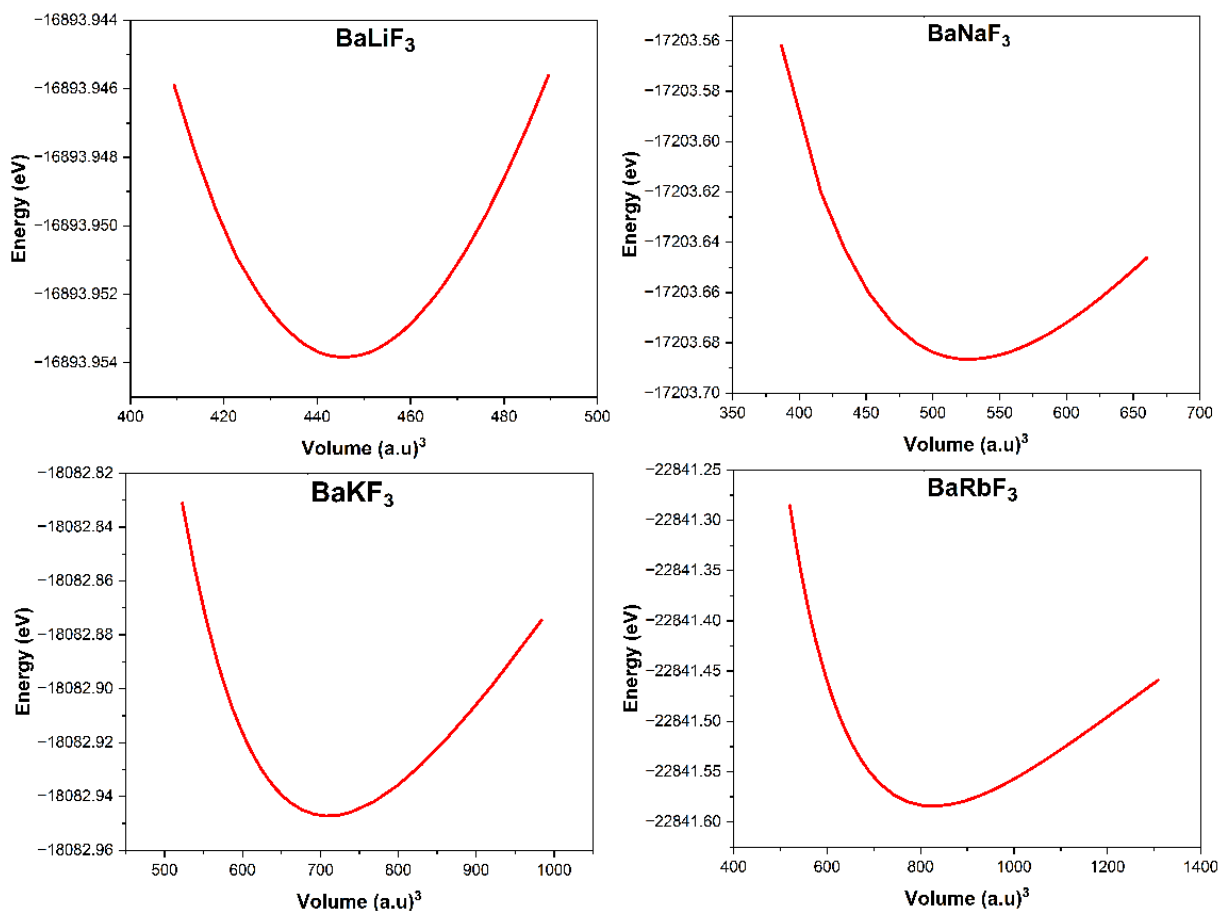


Figure 2. Optimization curves of BaYF₃ compounds, where Y denotes the elements Li, Na, K, and Rb.

at specific K -vectors in the CB and VB, and the delta function δ to keep energy and momentum conservation through the emission and absorption transitions of photons between electronic states.

The real component $\varepsilon_1(\omega)$ is related to the polarization of BaYF_3 compounds under the influence of incident light waves [32], as displayed in Figure 5 a. The spectra exhibit

two notable positive peaks for each Y-site within BaYF_3 . These peaks are positioned at 9.8 and 18.5 eV for $Y = \text{Li}$, 8.8 and 18.5 eV for $Y = \text{Na}$, 7.2 and 18.7 eV for $Y = \text{K}$, and 6.5 and 18.8 eV for $Y = \text{Rb}$. When the photon energy rises, the real part curve consistently decreases and reaches its minimum negative values with an arbitrary unit at about -3.16 at 19.8 eV, -3.68 at 19.5 eV, -4.36 at 19.4 eV, and

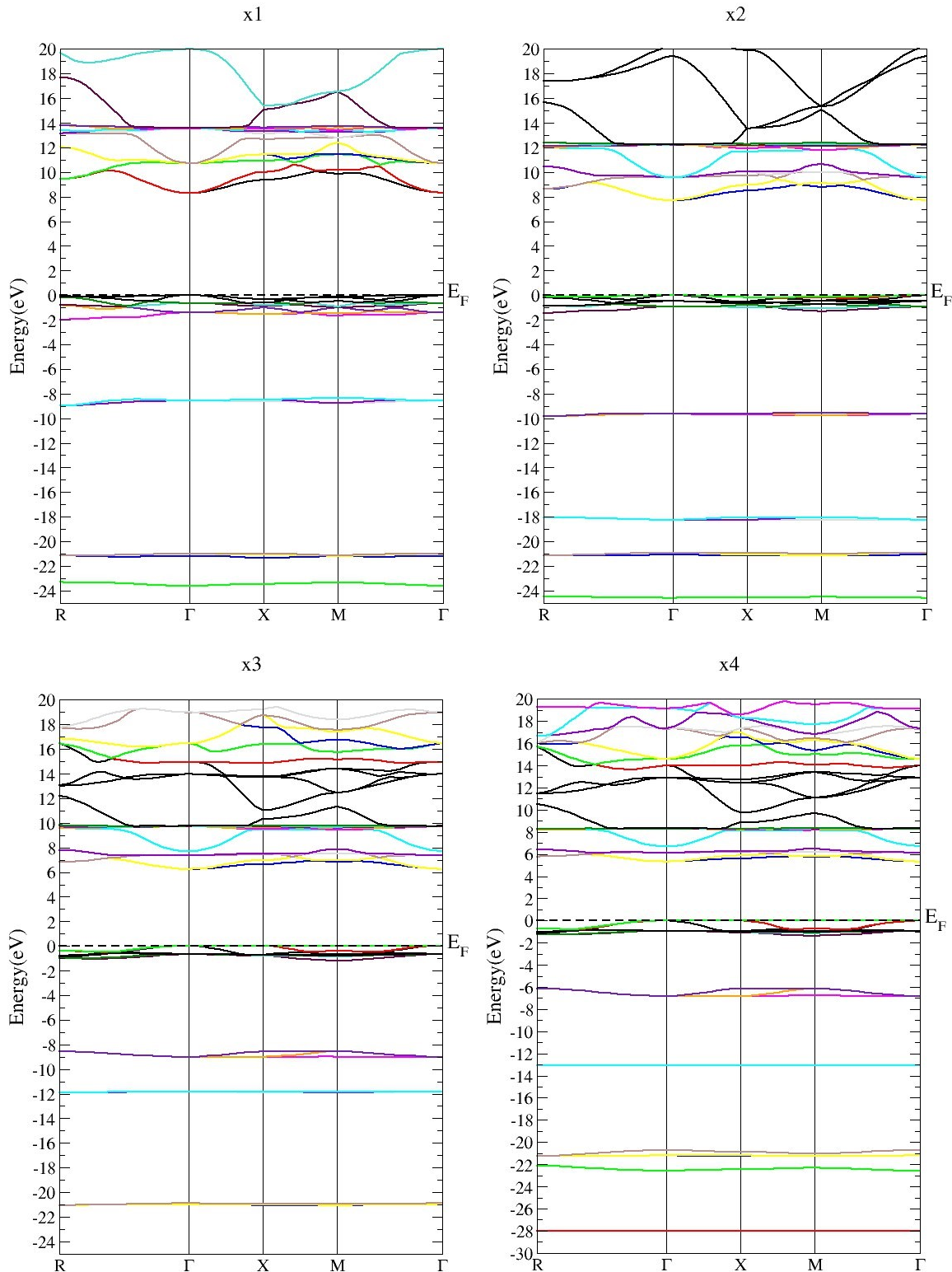


Figure 3. Band structure of the BaYF_3 compounds, where Y denotes the elements Li, Na, K, and Rb.

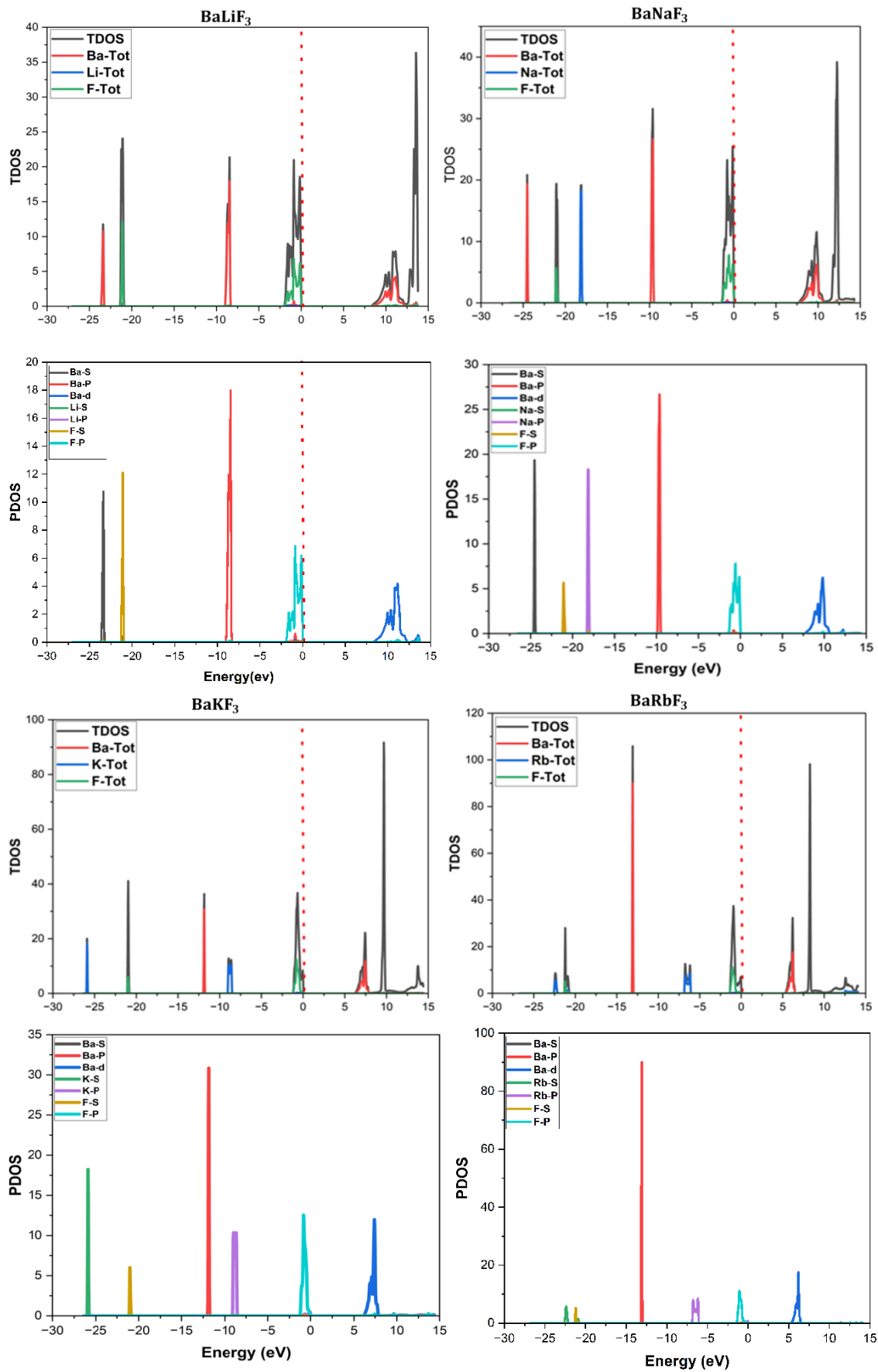


Figure 4. TDOS and PDOS of bulk BaYF_3 ($Y = \text{Li, Na, K, and Rb}$) within TB-mBJ approximation.

−4.44 at 19.38 for Y = Li, Na, K, and Rb, respectively. These negative values of $\epsilon_1(\omega)$ related to the plasmonic vibrations of the insulating perovskite BaYF₃ compounds at high energy since these compounds lose their dielectric properties at these ranges of energy and become like semiconductors [3, 33]. At the zero frequency limits, the static dielectric function values for BaLiF₃, BaNaF₃, BaKF₃, and BaRbF₃ are approximately 1.95, 1.8, 1.8, and 1.79, respectively.

The dielectric function $\epsilon_2(\omega)$ is concerned with the absorption (electronic transitions) in the BaYF₃ compounds when subjected to appropriate electromagnetic radiation [32]. As shown in Figure 5 b, the analysis of $\epsilon_1(\omega)$ spectra for these compounds reveals noticeable peaks at 10.8 eV for BaLiF₃, 10.3 eV for BaNaF₃, 8 eV for BaKF₃, and 7 eV for BaRbF₃. The highest peaks of $\epsilon_2(\omega)$ for these compounds are confined between 19 and 20 eV. These sharp peaks correspond to electronic transitions that occur between F-2*P* states located at the VB maxima and Ba-5*d* states at the CB minima. These transitions occur at the direct ($\Gamma - \Gamma$) energy band gap. The threshold energies are around 4.8 eV for BaLiF₃, 4 eV for BaNaF₃, 2.9 eV for BaKF₃, and 2.5 eV for BaRbF₃, which corresponds with the expected values acquired by Mubarak [15].

Figures 5 a and 5 b show that at high energies, the $\epsilon_1(\omega)$ and $\epsilon_2(\omega)$ spectrums behave in opposing trends. This is because the Kramers-Kronig relationship provides a correlation between the $\epsilon_1(\omega)$ and $\epsilon_2(\omega)$ parts [34]. This means that when the value of the imaginary portion changes significantly, the real part also changes noticeably. In Figure 5 b, the sharp peaks of the $\epsilon_2(\omega)$ at energy range from 19 to 20 eV mean the absorption and electronic transitions at their maximum states, which influence the $\epsilon_1(\omega)$ to get negative values, indicating that an enormous amount of energy is dissipated, which leads to a reduction in the overall polarization and energy storage in these compounds [35].

The optical characteristics of BaYF₃ in the xx-direction, which include the refractive index $n(\omega)$, absorption coefficient $\alpha(\omega)$, extinction coefficients $K(\omega)$, and reflectivity $R(\omega)$, were studied employing the derived real and imagi-

nary components, $\epsilon_1(\omega)$ and $\epsilon_2(\omega)$, of the dielectric function based on the following relation [31]:

$$n(\omega) = \frac{1}{\sqrt{2}} \sqrt{(\epsilon_1^2(\omega) + \epsilon_2^2(\omega))^{1/2} + \epsilon_1(\omega)} \quad (3)$$

$$\alpha(\omega) = \frac{2\omega}{c} K(\omega) \quad (4)$$

$$K(\omega) = \frac{1}{\sqrt{2}} \sqrt{(\epsilon_1^2(\omega) + \epsilon_2^2(\omega))^{1/2} - \epsilon_1(\omega)} \quad (5)$$

$$R(\omega) = \left| \frac{\sqrt{\epsilon_1(\omega) + i\epsilon_2(\omega)} - 1}{\sqrt{\epsilon_1(\omega) + i\epsilon_2(\omega)} + 1} \right| \quad (6)$$

The ($n(\omega)$: refractive index) is a fundamental parameter for calculating the degree of light refraction of BaYF₃ compounds, as shown in Figure 6 a. The evaluated ($n(0)$: static refractive index) is 1.4 for BaLiF₃, 1.34 for BaNaF₃, 1.34 for BaKF₃, and 1.33 for BaRbF₃, respectively. At low energies, the refractive index of BaYF₃ (Y = Li, Na, K, and Rb) compounds is most significant at 2.03 at 10.2 eV, 1.9 at 8.9 eV, 1.79 at 7.3 eV, and 1.73 at 6.57 eV, respectively. While at high energies, the maximum points are approximately 2.07 at 19.4 eV, 2.2 at 19.3 eV, 2.4 at 18.8 eV, and 2.56 at 18.9 eV, respectively. Due to interactions with electrons, photons are retarded as they enter a substance, resulting in $n(\omega) > 1$. Photons are slowed to a greater extent as they pass through materials with a higher refractive index. $n(\omega)$ is often increased if the electron density of a compound is increased [6].

The absorption coefficient $\alpha(\omega)$ in Figure 6 b is calculated based on the dielectric function and provides information about the absorption threshold. It measures how much light with a certain energy can travel through a medium without getting absorbed. The imaginary component depicted in Figure 5 b corresponds to the absorption coefficient. The optical response of BaLiF₃ is recognized within the energy range of 8.3 – 30 eV, while for BaNaF₃, it is recognized within the range of 7.75 – 30 eV. Similarly, BaKF₃ exhibits an optical response in the range of 6.27 – 30 eV, and BaRbF₃ shows an optical response in the range of 5.35 – 30

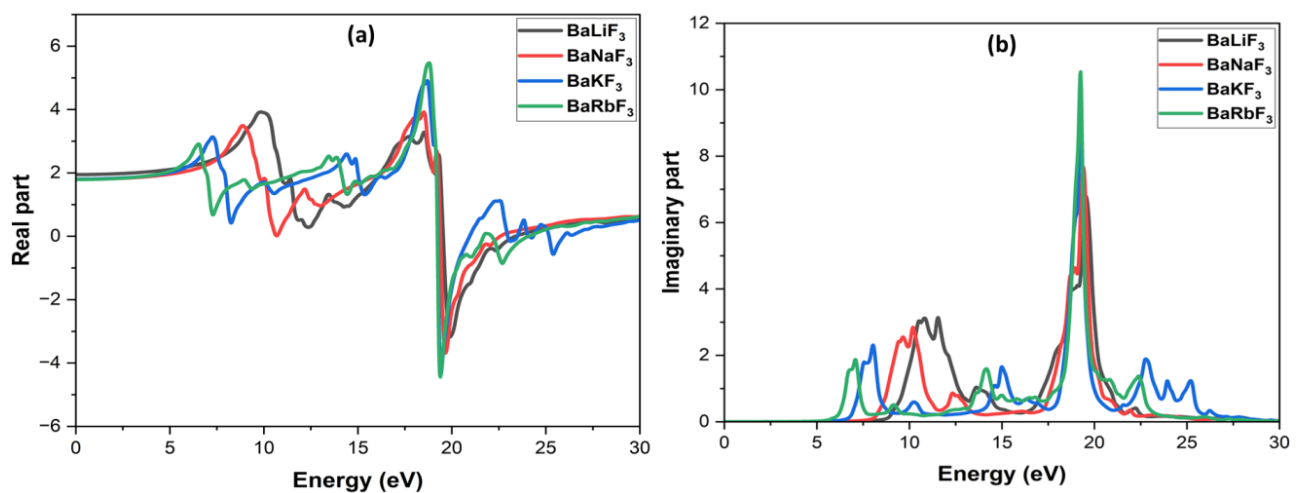


Figure 5. The determined (a) real and (b) imaginary parts of BaYF₃ compounds, where Y denotes the elements Li, Na, K, and Rb.

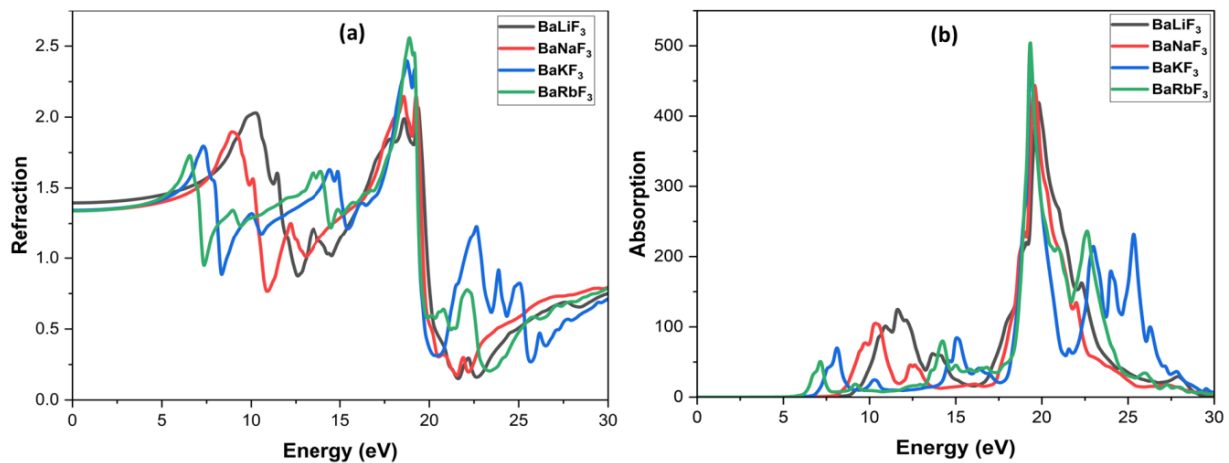


Figure 6. The determined (a) refraction index and (b) absorption coefficient of BaYF_3 compounds, where Y denotes the elements Li, Na, K, and Rb.

eV. It is worth noting that these materials do not exhibit any optical response below the respective band gap values of 8.3 eV, 7.75 eV, 6.27 eV, and 5.35 eV. These compounds exhibit their highest sensitivity at an energy range of 19–20 eV. These findings indicate that BaYF_3 perovskites have the possibility of being optoelectronic devices in the UV region of the radiation spectrum.

The behavior of the extinction coefficient $K(\omega)$ in Figure 7 a and the spectrum of $\epsilon_2(\omega)$ in Figure 5 b show a similar trend. The highest peaks of $K(\omega)$ exist as follows: 2.09 at 19.76 eV, 2.23 at 19.57 eV, 2.48 at 19.36 eV, and 2.57 at 19.33 eV for $Y = \text{Li, Na, K, and Rb}$, respectively. These values correspond to the real $\epsilon_1(\omega)$ values at zero frequency. However, it should be noted that they exceed values generated by PBE-GGA calculations, as mentioned in reference [15]. The reflectivity $R(\omega)$ characterizes the surface's capacity to reflect the incoming electromagnetic radiation. Results exhibited in Figure 7 b indicate that the reflectivity of BaYF_3 compounds reaches its maximum peaks at low energies (0–12 eV) at around 10% and 19%. On the other hand, the lowest reflectivity values for BaLiF_3 are located at about

13–15.5 eV, 11.4–14 eV for BaNaF_3 , 7.5–8.5 eV for BaNaF_3 , and for BaRbF_3 , they fell within 8.5–11 eV energy range. The reflectance spectrum of these compounds exhibits the greatest peaks as we move toward the UV spectrum at high energies, specifically about 71% for BaLiF_3 , 63% for BaNaF_3 , 61% for BaKF_3 , and 56% for BaRbF_3 . When the real part $\epsilon_1(\omega)$ starts to display negative values, as shown in Figure 5 a, the reflectivity spectrum reaches its highest points, since the negative values indicate that the materials are reflecting all incident electromagnetic waves [39].

3.4 Elastic properties

The elastic characteristics of BaYF_3 compounds were checked by calculating the elastic constants (ECs) by adopting the WC-GGA functional. The ECs C_{ij} play a vital function in describing the mechanical features of a substance, clarifying how it undergoes deformation when subjected to stress and subsequently recovers its original position after stress release [40]. It is commonly known that cubic crystals are identified by three unique elastic constants, denoted as

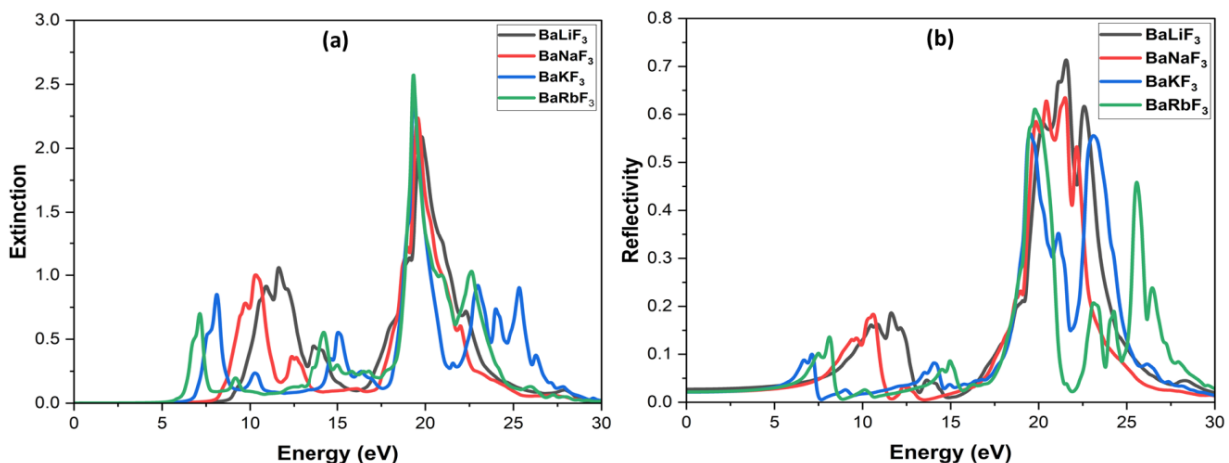


Figure 7. The determined (a) extinction coefficient and (b) reflectivity of BaYF_3 compounds, where Y denotes the elements Li, Na, K, and Rb.

(C_{ij} ; where $ij = 11, 22, \text{ and } 44$). The C_{ij} values in a cubic crystal are limited by constraints imposed by the demands of mechanical stability [41].

$$C_{11} + 2C_{12} > 0; C_{11} - C_{12} > 0; C_{11} > 0; C_{44} > 0$$

The above requirements are achieved by the estimated C_{ij} outcomes in Table 3, which means that the perovskite BaYF_3 with ($Y = \text{Li, Na, K, and Rb}$) are mechanically stable. The C_{11} value for BaLiF_3 is 138.72 GPa, and 144.75 GPa for BaNaF_3 which are higher than the values of BaKF_3 and BaRbF_3 . Thus, BaLiF_3 and BaNaF_3 are harder compared with other compounds. Depending on C_{11} values, the hardness of the BaYF_3 crystal decreases as we substitute the Y-site from Li to Rb. As possible as we know, there are no reported C_{ij} values that can be compared to our data, except for BaLiF_3 , which both theoretical and experimental previous data are explained in Table 3. There are many elastic properties connected with C_{ij} of the materials that can be determined from Voigt-Reuss-Hill equations as outlined below [3, 42].

$$\text{Bulkmodulus}(B) = \frac{1}{3}(C_{11} + 2C_{12}) \quad (7)$$

$$\text{Young's modulus}(Y) = \frac{9BG}{G + 3B} \quad (8)$$

$$\text{Shear modulus}(G) = \frac{1}{2}(G_R + G_V) \quad (9)$$

$$\text{Anisotropy ratio}(A) = \frac{2C_{44}}{C_{11} - C_{12}} \quad (10)$$

$$\text{Poisson's ratio}(\nu) = \frac{3B - 2G}{2(G + 3B)} \quad (11)$$

Table 3 provides elastic parameters computed for BaYF_3 compounds and related elastic properties, which are calculated using Eqs. (7) - (11). The bulk modulus “ B ” gives an

insight into the compound’s resistance to volume changes. According to Table 3, the bulk modulus of BaLiF_3 is 77.15 GPa, 61.89 GPa for BaNaF_3 , 40.69 GPa for BaKF_3 , and 34.77 GPa for BaRbF_3 . The structures of BaLiF_3 and BaNaF_3 compounds have a higher bulk modulus, indicating that they are less compressible than other compounds. There is a clear distinction between B values, which are calculated from C_{ij} and B_o values, which are derived from the Murnaghan equation in Table 1. This discrepancy arises because different approximations are used, specifically WC-GGA for elastic characteristics and GGA-PBE for structural properties. Young’s modulus (Y) is a reliable measure to characterize a material’s stiffness. A higher value of stiffness correlates to an increased level of rigidity for a specific material [43]. Based on the current findings of Y , we can conclude that BaLiF_3 and BaNaF_3 are stiffer than BaKF_3 and BaRbF_3 . The toughness of the structure is represented by the shear modulus (G). As we see from the results in Table 3, BaLiF_3 is the hardest material, having a shear modulus of 46.99 GPa, compared with other compounds. This indicates that the BaLiF_3 compound has significant resistance to deformation. The induction of microcracks in solids is closely connected to the elastic anisotropy of crystals, which carries substantial implications for the engineering analysis of materials [44]. The anisotropy nature of BaYF_3 compounds is determined through the anisotropy factor (A), since compounds with $A = 1$ are completely isotropic, whereas $1 > A > 1$ indicates anisotropy. This led us to know that all our compounds show elastic anisotropy, but BaLiF_3 is more anisotropic than BaNaF_3 , BaKF_3 , and BaRbF_3 compounds [42]. Using Poisson’s ratio (ν), ductile and brittle compounds were separated according to the value 0.26. Material getting a “ ν ” value lower than 0.26 is brittle, and vice versa [45]. Table 3 reveals that “ ν ” for BaLiF_3

Table 3. Results of elastic constants C_{ij} , bulk modulus, Young’s modulus, and shear modulus (in GPa) and (anisotropic ratio, Poisson’s ratio, and Pugh’s ratio) of BaYF_3 ($Y = \text{Li, Na, K, and Rb}$) compounds.

Compounds	C_{11}	C_{12}	C_{44}	B	Y	G	A	ν	B/G
BaLiF₃									
This work	138.72	46.37	47.56	77.15	117.18	46.99	1.03	0.246	1.64
Theoret [36]	118.88	42.76	43.19	68.14	102.57	41.06	1.14	0.25	1.66
Theoret [37]	134.0	45.4	46.5	74.9		45.6			
Theoret [38]	163.84	50.81	60.02	88.84					
Exp [25]	130	46.5	48.7	79		45.9			
BaNaF₃									
This work	144.75	20.47	19.85	61.89	81.93	32.02	0.32	0.558	1.93
BaKF₃									
This work	115.16	3.46	0.87	40.69	33.15	12.15	0.015	0.364	3.35
BaRbF₃									
This work	101.53	1.4	8.61	34.77	48.28	19.03	0.17	0.269	1.83

is 0.246, 0.558 for BaNaF₃, 0.364 for BaKF₃, and 0.269 for BaRbF₃, indicating ductility for each compound except BaLiF₃, which appears to have a brittle nature. Pugh's ratio (B/G) is also a vital measure for assessing the brittleness and ductility of BaYF₃ compounds. It demonstrates ductility when the B/G ratio is greater than 1.75 and brittleness when the B/G ratio is lower than 1.75 [46]. The results gathered from the examination of perovskites BaYF₃ by Pugh's ratio are 1.64 for BaLiF₃, 1.93 for BaNaF₃, 3.35 for BaKF₃, and 1.83 for BaRbF₃. This means that BaLiF₃ is brittle, while BaNaF₃, BaKF₃, and BaRbF₃ compounds appear to have ductile behavior, which provides evidence of their ability to deform without breaking under external strain. As indicated in Table 3, our elastic results of BaLiF₃ appear to have good convergence with experimental and some other theoretical studies.

4. Conclusion

This study explores the structural, electronic, optical, and elastic characteristics of the barium-based fluoro-perovskite BaYF₃ (Y = Li, Na, K, or Rb) employing the TB-mBJ approximation. The bulk modulus lowers while the lattice constant increases throughout the transition from Li to Rb for the BaYF₃ crystal. These structural parameters demonstrate a reasonable correspondence with available theoretical studies. According to the electronic structure analysis, each of these four compounds showed an insulating property and a direct ($\Gamma - \Gamma$) band gap since changing elements from Li to Rb in the BaYF₃ crystal lowers the energy gap by displacing Ba-5*d* states to low energies. The refractive index and dielectric function with their real and imaginary components were studied. As we see, the main transitions occur between F-2*P* valence band states and Ba-5*d* conduction band states for each compound. The analysis of the absorption and reflectivity spectra of these materials revealed considerable values of absorption and reflectivity in the ultraviolet range. We also checked the elastic properties of BaYF₃ compounds by adopting WC-GGA functional. Based on the elastic data obtained, all compounds are stable. BaLiF₃ is brittle while other compounds are ductile; it is also found both BaLiF₃ and BaNaF₃ are harder than BaKF₃ and BaRbF₃, and all BaYF₃ compounds are elastic anisotropic.

Authors Contributions

Authors have contributed equally in preparing and writing the manuscript.

Availability of Data and Materials

The authors declare that the data supporting the findings of this study are available within the paper.

Conflict of Interests

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

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